

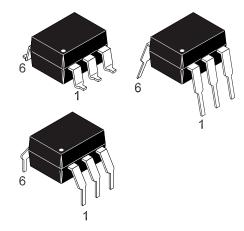
DESCRIPTION

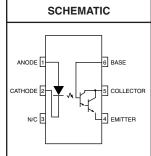
The 4N29, 4N30, 4N31, 4N32, 4N33 have a gallium arsenide infrared emitter optically coupled to a silicon planar photodarlington.

4N29 4N30 4N31 4N32 4N33

FEATURES

- High sensitivity to low input drive current
- Meets or exceeds all JEDEC Registered Specifications
- VDE 0884 approval available as a test option -add option .300. (e.g., 4N29.300)





APPLICATIONS

- Low power logic circuits
- Telecommunications equipment
- Portable electronics
- Solid state relays
- Interfacing coupling systems of different potentials and impedances.

Parameter	Symbol	Value	Units	
TOTAL DEVICE		55.4450	20	
Storage Temperature	T _{STG}	-55 to +150	°C	
Operating Temperature	T _{OPR}	-55 to +100	°C	
Lead Solder Temperature	T _{SOL}	260 for 10 sec	°C	
Total Device Power Dissipation @ T _A = 25°C	D	250	mW	
Derate above 25°C	P _D	3.3	mW/°C	
EMITTER		80	mA	
Continuous Forward Current	l _F	80		
Reverse Voltage	V _R	3	V	
Forward Current - Peak (300 µs, 2% Duty Cycle)	I _F (pk)	3.0	А	
LED Power Dissipation @ T _A = 25°C	В	150	mW	
Derate above 25°C	$$ P_{D}	2.0	mW/°C	
DETECTOR	D\/	30	V	
Collector-Emitter Breakdown Voltage	BV _{CEO}	30		
Collector-Base Breakdown Voltage	BV _{CBO}	30	V	
Emitter-Collector Breakdown Voltage	BV _{ECO}	5	V	
Detector Power Dissipation @ T _A = 25°C	В	150	mW	
Derate above 25°C	P _D	2.0	mW/°C	
Continuous Collector Current	I _C	150	mA	



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ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS						
Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
EMITTER	(I _E = 10 mA)	V _F		1.2	1.5	V
*Input Forward Voltage	(15 - 10 111/1)	\ \frac{1}{2}		1.2	1.0	·
*Reverse Leakage Current (V _R = 3.0 V)		I _R		0.001	100	μΑ
*Capacitance	$(V_F = 0 V, f = 1.0 MHz)$	С		150		pF
DETECTOR	(100 0)	D\/	30	60		
*Collector-Emitter Breakdown Voltage	$(I_C = 100 \mu A, I_B = 0)$	BV _{CEO}	30	60		
*Collector-Base Breakdown Voltage $(I_C = 100 \mu A,$		BV _{CBO}	30	100		V
*Emitter-Collector Breakdown Voltage	$(I_E = 100 \mu A, I_B = 0)$	BV _{ECO}	5.0	8		V
*Collector-Emitter Dark Current (V _{CE} = 10 V, Base Open)		I _{CEO}		1	100	nA
DC Current Gain	$(V_{CE} = 5.0 \text{ V}, I_{C} = 500 \mu\text{A})$	h _{FE}		5000		

TRANSFER CHARACTERISTICS							
DC Characteristic	Test Conditions	Symbol	Min	Тур	Max	Units	
*Collector Output Current ^(1,2) (4N32, 4N33)			50 (500)				
(4N29, 4N30)	$(I_F = 10 \text{ mA}, \ V_{CE} = 10 \ V, \ I_B = 0)$	I _C (CTR)	10 (100)			mA (%)	
(4N31)			5 (50)				
*Saturation Voltage ⁽²⁾ (4N29, 4N30, 4N32, 4N33) ($I_F = 8.0 \text{ mA}, I_C = 2.0 \text{ mA}$)		V			1.0	V	
		V _{CE(sat)}			1.2	V	

TRANSFER CHARACTERISTICS							
AC Characteristic		Test Conditions	Symbol	Min	Тур	Max	Units
Turn-on Time ⁽³⁾		(1 000 1 50 1) (10) (t _{on}			5.0	
Turn-off Time ⁽³⁾	(4N32, 4N33)	$(I_F = 200 \text{ mA}, I_C = 50 \text{ mA}, V_{CC} = 10 \text{ V})$				100	μs
(4N2	29, 4N30, 4N31)	(Fig.7)	Loff			40	
Bandwidth ^(4,5)			BW		30		KHz

ISOLATION CHARACTERISTICS						
Characteristic	Test Conditions	Symbol	Min	Тур	Max	Units
Input-Output Isolation Voltage ⁽⁶⁾ (4N29, 4N30, 4N31, 4N32, 4N33)	$(I_{I-O} \le 1 \mu A, Vrms, t = 1 min.)$	V	5300			Vac(rms)
*(4N32)	VDC	V _{ISO}	2500			\ \ \
*(4N33)	VDC	1	1500			1 '
Isolation Resistance ⁽⁶⁾ (V _{I-O} = 500 VDC)		R _{ISO}		10 ¹¹		Ω
Isolation Capacitance ⁽⁶⁾	$(V_{I-O} = \emptyset, f = 1 MHz)$	C _{ISO}		0.8		pf



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Fig. 1 Output Current vs. Input Current

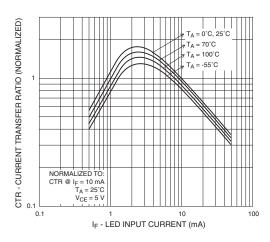


Fig. 2 Current Transfer Ratio vs. Ambient Temperature

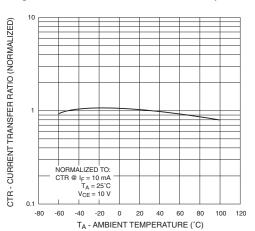


Fig. 3 Collector Current vs. Collector-Emitter Voltage

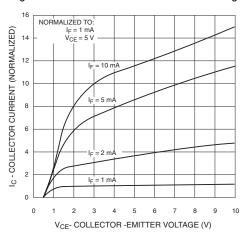


Fig. 4 Dark Current vs. Ambient Temperature

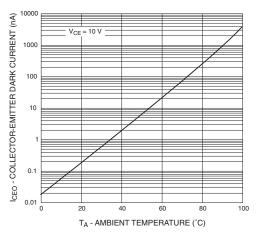


Fig. 5 Turn-On Time vs. Input Current

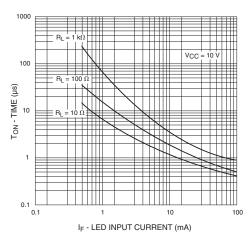
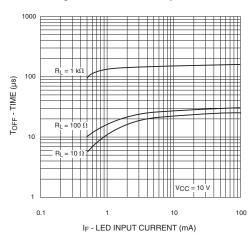
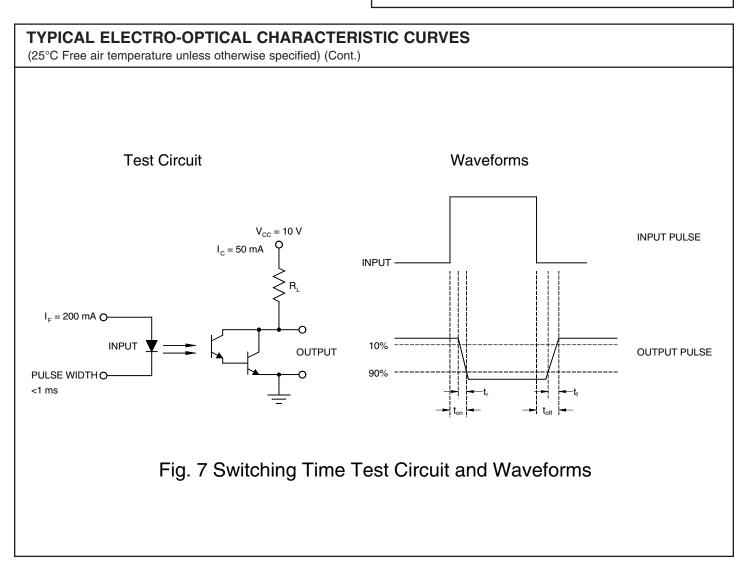


Fig. 6 Turn-Off Time vs. Input Current





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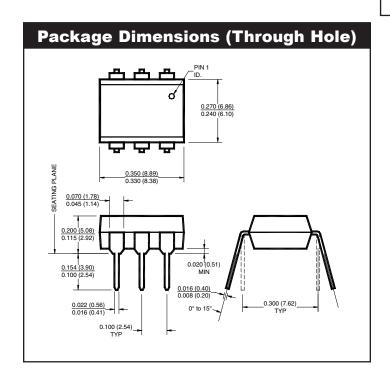


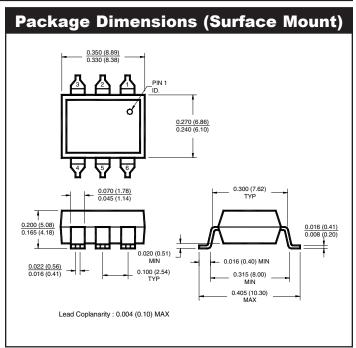
Notes

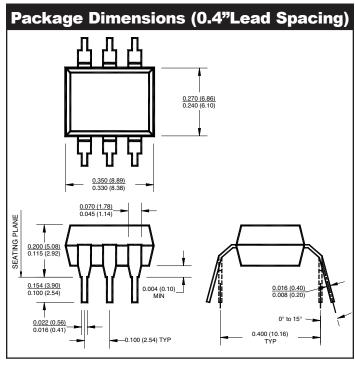
- * Indicates JEDEC registered data.
- 1. The current transfer $ratio(I_C/I_F)$ is the ratio of the detector collector current to the LED input current with V_{CE} @ 10 V.
- 2. Pulse test: pulse width = $300\mu s$, duty cycle $\leq 2.0\%$.
- 3. For test circuit setup and waveforms, refer to figure 7...
- 4. I_F adjusted to I_C = 2.0 mA and I_C = 0.7 mA rms.
- 5. The frequency at which I_C is 3dB down from the 1 KHz value.
- 6. For this test, LED pins 1 and 2 are common, and phototransistor pins 4,5 and 6 are common.

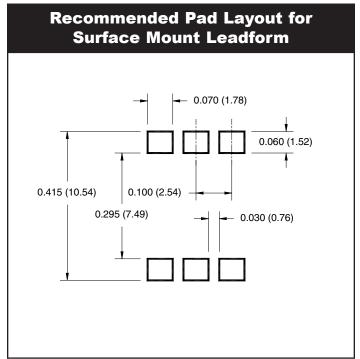


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NOTE

All dimensions are in inches (millimeters)

Call QT Optoelectronics for more information or the phone number of your nearest distributor.

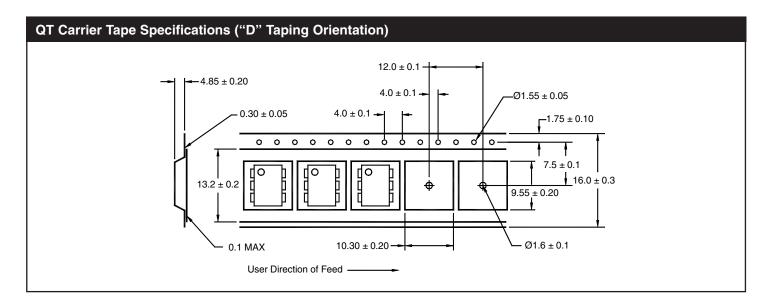
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4N29 4N30 4N31 4N32 4N33

ORDERING INFORMATION

Option	Order Entry Identifier	Description	
S	.S	Surface Mount Lead Bend	
SD	.SD	Surface Mount; Tape and reel	
W	.W	0.4" Lead Spacing	
300	.300	VDE 0884	
300W	.300W	VDE 0884, 0.4" Lead Spacing	
3S	.3\$	VDE 0884, Surface Mount	
3SD	.3SD	VDE 0884, Surface Mount, Tape & Reel	



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